

Schottky Barrier Diode, 100mA, 30V Type

### FEATURES

Ultra Small Package

# APPLICATIONS

Low Current Rectification

# ABSOLUTE MAXIMUM RATINGS

			Ta=25
PARMETER	SYMBOL	RATINGS	UNITS
Repetitive Peak Voltage	Vrm	30	V
Reverse Voltage (DC)	Vr	30	V
Forward Current (Average)	IF(AV)	100	mA
Peak Forward Surge Current <sup>*1</sup>	IFSM	0.6	А
Junction Temperature	Tj	125	
Storage Temperature Range	Tstg	-55 ~ +125	

\*1) 60Hz Half sine wave, 1 cycle, Non-Repetitive.

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PACKAGING INFORMATION



: 3(Product Number) a,b,c,d,e,d,e,f,g,h : Lot Number



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Unit: mm

воттом

45)

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## PRODUCT NAME

PRODUCT NAME	PACKAGE
XBS013S1CR-G	USP-2B02

The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully RoHS compliant. The device orientation is fixed in its embossed tape pocket.

# ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNITS
		TEST CONDITIONS	MIN.	TYP.	MAX.	
Forward Voltage	VF1	I <sub>F</sub> =100mA	-	0.71	1	V
Reverse Current	lr	V <sub>R</sub> =25V	-	-	2	μA

#### NOTES ON USE

1. Please keep away from mechanical stress to the product when mounting or after mounting.

2. If the IC is mounted close to a board break line or fixed in screws, the IC or its electrodes may be caused damage as results of board deformation and mechanical stress.

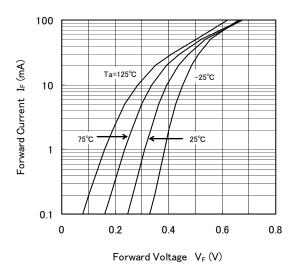
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Ta=25

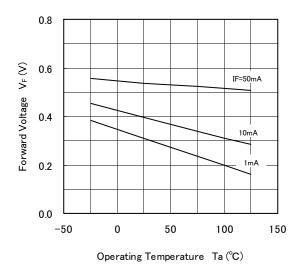
## **TYPICAL PERFORMANCE CHARACTERISTICS**

(1) Forward Current vs. Forward Voltage

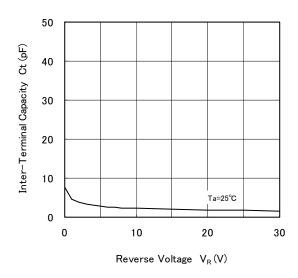
(2) Reverse Current vs. Reverse Voltage

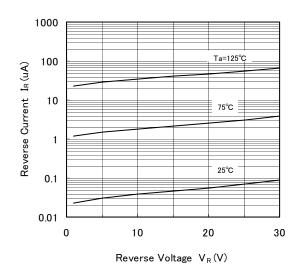


(3) Forward Voltage vs. Operating Temperature

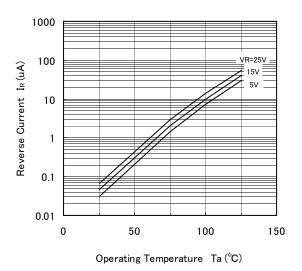


(5) Inter-Terminal Capacity vs. Reverse Voltage

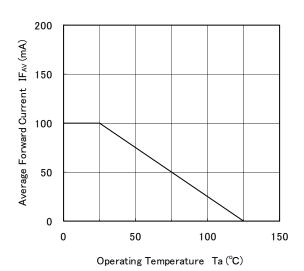




(4) Reverse Current vs. Operating Temperature



(6) Average Forward Current vs. Operating Temperature



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